

CMOS Digital Integrated Circuits Silicon Monolithic

# 74VHC240FT,74VHC244FT

#### 1. Functional Description

Octal Bus Buffer

74VHC240FT: INVERTED, 3-STATE OUTPUTS 74VHC244FT: NON-INVERTED, 3-STATE OUTPUTS

#### 2. General

The 74VHC240FT and 74VHC244FT are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C2MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74VHC240FT is an inverting 3-state buffer having two active-low output enables. The 74VHC244FT is a non-inverting 3-state buffer, and has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

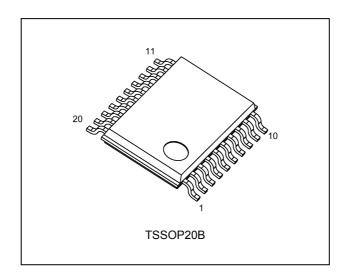
#### 3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C
- (3) High speed:  $t_{pd} = 3.9 \text{ ns}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- (4) Low power dissipation:  $I_{CC}$  = 4.0  $\mu A$  (max) at  $T_a$  = 25  $^{\circ}C$
- (5) High noise immunity:  $V_{NIH} = V_{NIL} = 28 \% V_{CC}$  (min)
- (6) Power down protection is provided on all inputs.
- (7) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (8) Wide operating voltage range:  $V_{CC(opr)} = 2.0 \text{ V}$  to 5.5 V
- (9) Low noise:  $V_{OLP} = 0.8 \text{ V (max)}$
- (10) Pin and function compatible with the 74 series (AC/HC/AHC/LV etc.) 240 or 244 type.

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

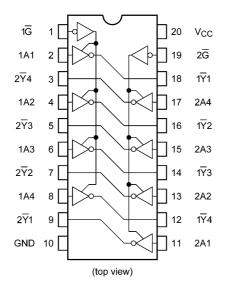


# 4. Packaging

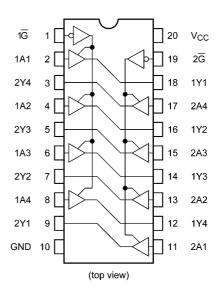


# 5. Pin Assignment

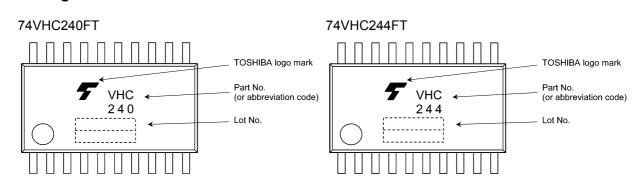
74VHC240FT



#### 74VHC244FT



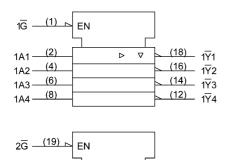
# 6. Marking





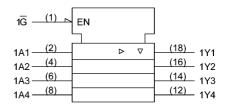
### 7. IEC Logic Symbol

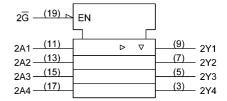
#### 74VHC240FT



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#### 74VHC244FT





#### 8. Truth Table

Input G	Input A <sub>n</sub>	Input A <sub>n</sub> Output Y <sub>n</sub>	
L	L	L	Н
L	Н	Н	L
Н	Х	Z	Z

(9) 2<u>Y</u>1

(7) 2<del>7</del>2

(5) 2<del>7</del>3

(3) 2<del>Y</del>4

X: Don't careZ: High impedanceYn: 74VHC244FT

(11)

(13)

(15)

2A2

2A3

2A4 <u>(17)</u>

Yn: 74VHC240FT

## 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 7.0	V
Output voltage	V <sub>OUT</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	lok		±20	mA
Output current	l <sub>out</sub>		±25	mA
V <sub>CC</sub> /ground current	Icc		±75	mA
Power dissipation	$P_D$	(Note 1)	180	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of  $T_a$  = -40 to 85 °C. From  $T_a$  = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.



# 10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>		2.0 to 5.5	V
Input voltage	V <sub>IN</sub>		0 to 5.5	V
Output voltage	V <sub>OUT</sub>		0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>		-40 to 125	°C
Input rise and fall times	dt/dv	$V_{CC}$ = 3.3 $\pm$ 0.3 $V$	0 to 100	ns/V
		V <sub>CC</sub> = 5 ± 0.5 V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

#### 11. Electrical Characteristics

# 11.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	_	V
				3.0 to 5.5	V <sub>CC</sub> × 0.7	_	_	
Low-level input voltage	V <sub>IL</sub>	_		2.0	_	_	0.50	V
				3.0 to 5.5	_	_	$V_{CC} \times 0.3$	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	2.0	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I <sub>OH</sub> = -4 mA	3.0	2.58	_	_	
			I <sub>OH</sub> = -8 mA	4.5	3.94	_	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			$I_{OL}$ = 4 mA	3.0	_		0.36	
			$I_{OL}$ = 8 mA	4.5	_	1	0.36	
3-state output OFF-state leakage current	l <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	_	±0.25	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	_	±0.1	μΑ
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	μΑ



# 11.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	V
				3.0 to 5.5	V <sub>CC</sub> × 0.7	_	
Low-level input voltage	V <sub>IL</sub>	_		2.0	_	0.50	V
				3.0 to 5.5	_	V <sub>CC</sub> × 0.3	]
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	1 I
				4.5	4.4	_	1
			I <sub>OH</sub> = -4 mA	3.0	2.48	_	
			I <sub>OH</sub> = -8 mA	4.5	3.80	_	1 I
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	1 I
			I <sub>OL</sub> = 4 mA	3.0	_	0.44	
			I <sub>OL</sub> = 8 mA	4.5	_	0.44	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±2.50	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND	_	0 to 5.5		±1.0	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	40.0	μА

# 11.3. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 125 °C)

Characteristics	Symbol	Test Condition	on	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	V
				3.0 to 5.5	V <sub>CC</sub> × 0.7	_	
Low-level input voltage	V <sub>IL</sub>	_		2.0	_	0.50	V
				3.0 to 5.5	_	$V_{CC} \times 0.3$	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			$I_{OH} = -4 \text{ mA}$	3.0	2.40	_	
			I <sub>OH</sub> = -8 mA	4.5	3.70	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I <sub>OL</sub> = 4 mA	3.0	_	0.55	
			I <sub>OL</sub> = 8 mA	4.5	_	0.55	
3-state output OFF-state leakage current	l <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±10.0	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5		±2.0	μΑ
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	80.0	μΑ



# 11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	74VHC240FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	_	5.3	7.5	ns
						50	_	7.8	11.0	
					5.0 ± 0.5	15	_	3.6	5.5	
						50	_	5.1	7.5	
Propagation delay time	74VHC244FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	_	5.8	8.4	ns
						50	_	8.3	11.9	
					5.0 ± 0.5	15	_	3.9	5.5	
						50	_	5.4	7.5	
3-state output enable time		t <sub>PZL</sub> ,t <sub>PZH</sub>		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	15	_	6.6	10.6	ns
						50	_	9.1	14.1	
					5.0 ± 0.5	15	_	4.7	7.3	
						50	_	6.2	9.3	
3-state output disable time		$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	50	_	10.3	14.0	ns
					5.0 ± 0.5	50	_	6.7	9.2	
Output skew		t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$3.3 \pm 0.3$	50	_	_	1.5	ns
					5.0 ± 0.5	50	_	_	1.0	
Input capacitance		C <sub>IN</sub>		_			_	4	10	pF
Output capacitance		C <sub>OUT</sub>					_	6	_	pF
Power dissipation	74VHC240FT	C <sub>PD</sub>	(Note 2)	_			_	17	_	pF
capacitance	74VHC244FT						_	19	_	

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m - t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m - t_{PHL}n|$ )

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$  (per bit)

## 11.5. AC Characteristics

### (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	74VHC240FT	$t_{PLH}, t_{PHL}$		_	$3.3 \pm 0.3$	15	1.0	9.0	ns
						50	1.0	12.5	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
Propagation delay time	74VHC244FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	1.0	10.0	ns
						50	1.0	13.5	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
3-state output enable time		$t_{PZL}, t_{PZH}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	15	1.0	12.5	ns
						50	1.0	16.0	
					5.0 ± 0.5	15	1.0	8.5	
						50	1.0	10.5	
3-state output disable time		$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	50	1.0	16.0	ns
					5.0 ± 0.5	50	1.0	10.5	
Output skew		t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$3.3 \pm 0.3$	50	-	1.5	ns
					5.0 ± 0.5	50	-	1.0	
Input capacitance		C <sub>IN</sub>		_				10	pF

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 



# 11.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

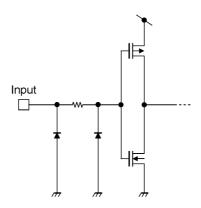
Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	74VHC240FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	1.0	10.5	ns
						50	1.0	14.0	
					5.0 ± 0.5	15	1.0	7.5	
						50	1.0	9.5	
Propagation delay time	74VHC244FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	1.0	11.5	ns
						50	1.0	15.0	
					$5.0 \pm 0.5$	15	1.0	7.5	
						50	1.0	9.5	
3-state output enable time		$t_{PZL}, t_{PZH}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	15	1.0	14.0	ns
						50	1.0	17.5	
					$5.0 \pm 0.5$	15	1.0	10.0	
						50	1.0	12.0	
3-state output disable time		$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	50	1.0	17.5	ns
					$5.0 \pm 0.5$	50	1.0	11.5	
Output skew		t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$3.3\pm0.3$	50		1.5	ns
					$5.0 \pm 0.5$	50		1.0	
Input capacitance		C <sub>IN</sub>		_			_	10	pF

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 

# 11.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.5	-0.8	V
Minimum high-level dynamic input voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0	_	3.5	V
Maximum low-level dynamic input voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0	_	1.5	V

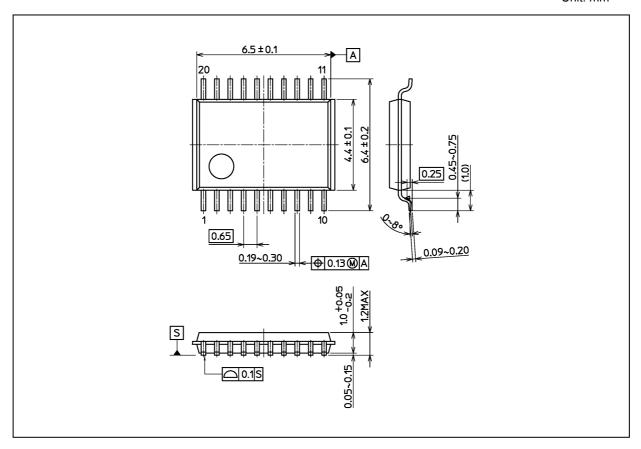
# 11.8. Internal Equivalent Circuit





# **Package Dimensions**

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	



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